Absolute Maximum Ratings, T_A = 25 °C (Unless Otherwise Noted)

Rating	Symbol	Value	Unit
'3070		±58	
'3080		±65	
'3095		±75	
'3115		±90	
'3125		±100	
'3145	Voon	±120	
Repetitive peak off-state voltage, (terminals 1-2 and 3-2)		±135	V
3180	J	±145	
'3200 '3219		±155 ±180	
3219		±180 ±190	
3250		±190 ±220	
3350		±275	
'3395		±320	
Non-repetitive peak on-state pulse current (see Notes 1 and 2)			
2/10 (Telcordia GR-1089-CORE, 2/10 voltage wave shape)		2x250 2x250	
8/20 (IEC 61000-4-5, combination wave generator, 1.2/50 voltage wave shape)			
10/160 (TIA/EIA-IS-968 (replaces FCC Part 68), 10/160 us voltage wave shape)		2x150	
5/310 (ITU-T K.44, 10/700 μs voltage wave shape used in K.20/.45/.21)	I _{PPSM}	2x120	Α
5/320 (TIA/EIA-IS-968 (replaces FCC Part 68), 9/720 us voltage wave shape)		2x120	
10/560 (TIA/EIA-IS-968 (replaces FCC Part 68), 10/560 us voltage wave shape)		2x100	
10/1000 (Telcordia GR-1089-CORE, 10/1000 voltage wave shape)		2x80	
Non-repetitive peak on-state current (see Notes 1 and 2)			
50 Hz, 1 cycle		2x25	_
60 Hz, 1 cycle	I _{TSM}	2x30	Α
1000 s 50 Hz/60 Hz a.c.		2x1.2	
Initial rate of rise of on-state current, Linear current ramp, Maximum ramp value < 50 A	di _T /dt	500	A/μs
Junction temperature	T _J	-40 to +150	°C
Storage temperature range	T _{stg}	-65 to +150	°C

NOTES: 1. Initially, the device must be in thermal equilibrium with T_J = 25 °C.

Recommended Operating Conditions

Component	Min	Тур	Max	Unit
Series resistor for GR-1089-CORE first-level surge survival	5			
Series resistor for ITU-T recommendation K.20/.45/.21 (coordination with 400 V GDT at 4 kV)	6.4			
R1, R2 Series resistor for TIA/EIA-IS-968 (replaces FCC Part 68) 9/720 survival	0			Ω
Series resistor for TIA/EIA-IS-968 (replaces FCC Part 68) 10/560 survival	0			
Series resistor for TIA/EIA-IS-968 (replaces FCC Part 68) 10/160 survival	2.5			

^{2.} These non-repetitive rated currents are peak values of either polarity. The rated current values are applied to the terminals 1 and 3 simultaneously (in this case the terminal 2 return current will be the sum of the currents applied to the terminals 1 and 3). The surge may be repeated after the device returns to its initial conditions.

Electrical Characteristics for the 1 and 2 or the 3 and 2 Terminals, T_A = 25 °C

	Parameter	Test Conditions	Min	Тур	Max	Unit
	Repetitive peak off-	T _A = 25 °C			±5	μΑ
I _{DRM}	state current	$V_{D} = V_{DRM}$ $T_{A} = 85 ° C$			±10	μΑ
		'3070			±70	
		'3080			±80	
		'3095			±95	
		'3115			±115	
		'3125			±125	
		'3145			±145	
V	AC breakover voltage	$dv/dt = \pm 250 \text{ V/ms}, R_{SOURCE} = 300 \Omega$ (3165)			±165	V
$V_{(BO)}$	Ac breakover voltage	3180 '3180'			±180	V
		'3200			±200	
		'3219			±219	
		3250			±250	
		'3290			±290	
		'3350			±350	
		3395			±395	
		'3070			±81	
		'3080 '3095			±91	
					±107	
		'3115			±128	
		'3125			±138	
		dv/dt ≤1000 V/μs, Linear voltage ramp, '3145			±159	
V	Ramp breakover	Maximum ramp value = ±500 V 3165			±179	V
$V_{(BO)}$	voltage	$di/dt = \pm 20$ A/µs, Linear current ramp, '3180			±195	V
		Maximum ramp value = ±10 A '3200			±215	
		'3219			±234	
		'3250			±265	
		'3290			±304	
		'3350			±361	
		'3395		<u> </u>	±403	
I _(BO)	Breakover current	$dv/dt = \pm 250 \text{ V/ms}, \text{ R}_{SOURCE} = 300 \Omega$			±800	mA
Ι _Η	Holding current	$I_T = \pm 5A$, di/dt = +/-30 mA/ms	±150			mA
dv/dt	Critical rate of rise of off-state voltage	Linear voltage ramp, Maximum ramp value < 0.85V _{DRM}	±5			kV/μs
I _D	Off-state current	$V_D = \pm 50 \text{ V}$ $T_A = 85 ^{\circ}\text{C}$			±10	μΑ

TISP3xxxT3BJ Overvoltage Protector Series

BOURNS®

Electrical Characteristics for the 1 and 2 or the 3 and 2 Terminals, T_A = 25 °C (Continued)

	Parameter		Test Condition	ns	Min	Тур	Max	Unit
		f = 1 MHz,	$f = 1 \text{ MHz}, Vd = 1 \text{ V rms}, V_D = 0,$	'3070 thru '3095		95	114	
				'3115 thru '3219		69	83	
				'3250 thru '3395		51	62	
		f = 1 MHz,	$Vd = 1 V rms, V_D = -1 V$	'3070 thru '3095		90	108	
				'3115 thru '3219		63	76	
	C _{off} Off-state capacitance			'3250 thru '3395		46	55	
		f = 1 MHz,	$Vd = 1 V rms, V_D = -2 V$	'3070 thru '3095		83	100	nE
Coff				'3115 thru '3219		59	70	pF
				'3250 thru '3395		42	51	
		f = 1 MHz,	$Vd = 1 V rms, V_D = -50 V$	'3070 thru '3095		43	51	
			_	'3115 thru '3219		29	35	
				'3250 thru '3395		20	24	
		f = 1 MHz,	$Vd = 1 V rms, V_D = -100 V$	'3250 thru '3395	121	16	19	
		(see Note 3	3)					

NOTE 3: These capacitance measurements employ a three terminal capacitance bridge incorporating a guard circuit. The unmeasured third terminal is connected to the guard terminal of the bridge.

Thermal Characteristics

Parameter			Test Conditions	Min	Тур	Max	Unit
R _{0JA} Junction to free air thermal resistance			51-3 PCB, I _T = I _{TSM(1000)} , (see Note 4)			90	°C/W

NOTE 4: EIA/JESD51-2 environment and PCB has standard footprint dimensions connected with 5 A rated printed wiring track widths.

Parameter Measurement Information

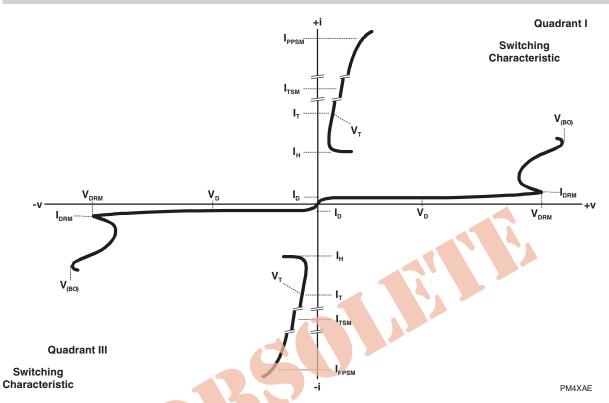


Figure 1. Voltage-Current Characteristic for Terminal Pairs 1-2 and 3-2
All Measurements are Referenced to Terminal 2

Typical Characteristics

OFF-STATE CURRENT VS JUNCTION TEMPERATURE TC4AH3AA 10 V_D = ±50 V 1 1 -25 0 25 50 75 100 125 150 T_J - Junction Temperature - °C

Figure 2.

ON-STATE CURRENT

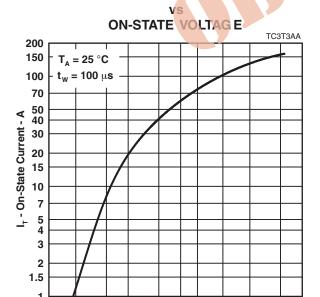


Figure 4.

V_T - On-State Voltage - V

3

415

15 20

NORMALIZED BREAKOVER VOLTAGE

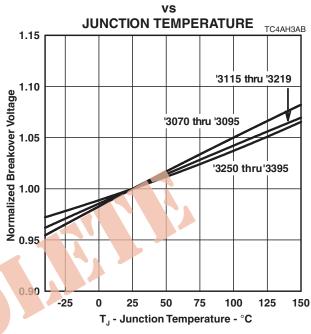


Figure 3.

NORMALIZED HOLDING CURRENT vs

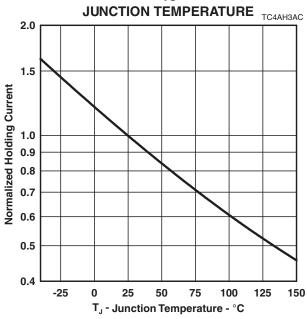


Figure 5.

0.7 1

Rating and Thermal Information

NON-REPETITIVE PEAK ON-STATE CURRENT

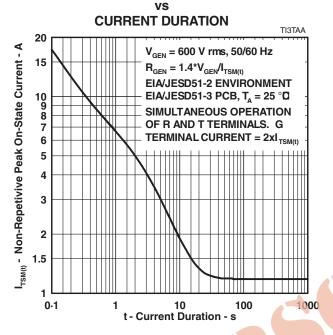


Figure 8.

V_{DRM} DERATING FACTOR

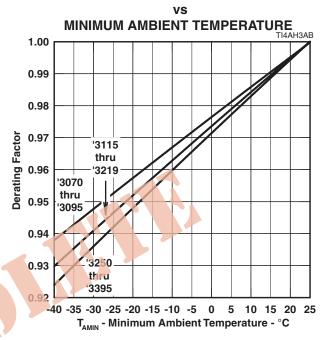
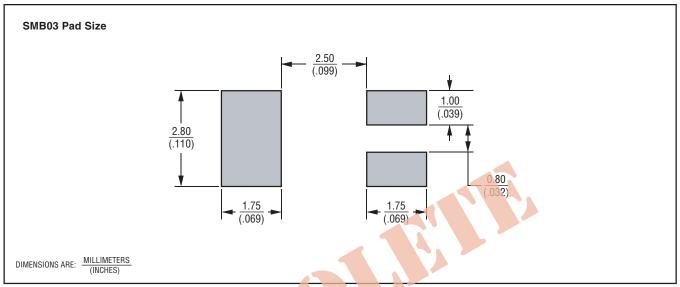


Figure 9.

MECHANICAL DATA

Recommended Printed Wiring Land Pattern Dimensions



MD3BJAAA

Device Symbolization Code

Devices will be coded as below.

Device	Symbolization Code
TISP3070T3	3070T3
TISP3080T3	3080T3
TISP3095T3	3095T3
TISP3115T3	3115T3
TISP3125T3	3125T3
TISP3145T3	3145T3
TISP3165T3	3165T3
TISP3180T3	3180T3
TISP3200T3	3200T3
TISP3219T3	3219T3
TISP3250T3	3250T3
TISP3290T3	3290T3
TISP3350T3	3350T3
TISP3395T3	3395T3

Carrier Information

For production quantities, the carrier will be embossed tape reel pack. Evaluation quantities may be shipped in bulk pack or embossed tape.

Package	Carrier	Standard Quantity
SMB	Embossed Tape Reel Pack	3000

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SEPTEMBER 2001 - REVISED MAY 2011

Specifications are subject to change without notice.
Customers should verify actual device performance in their specific applications.

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